

PANDA detector R&D study

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On behalf of the PANDA collaboration



Content



- Introduction
 - FAIR
 - PANDA physics
- PANDA detector
 - EMC
 - MVD
- Strategy



FAIR: Facility for Antiproton and Ion Research



GSI, Darmstadt

German National Lab for
Heavy Ion Research

Highlights:

- Heavy ion physics
- Nuclear physics
- Atomic & plasma physics
- Cancer research

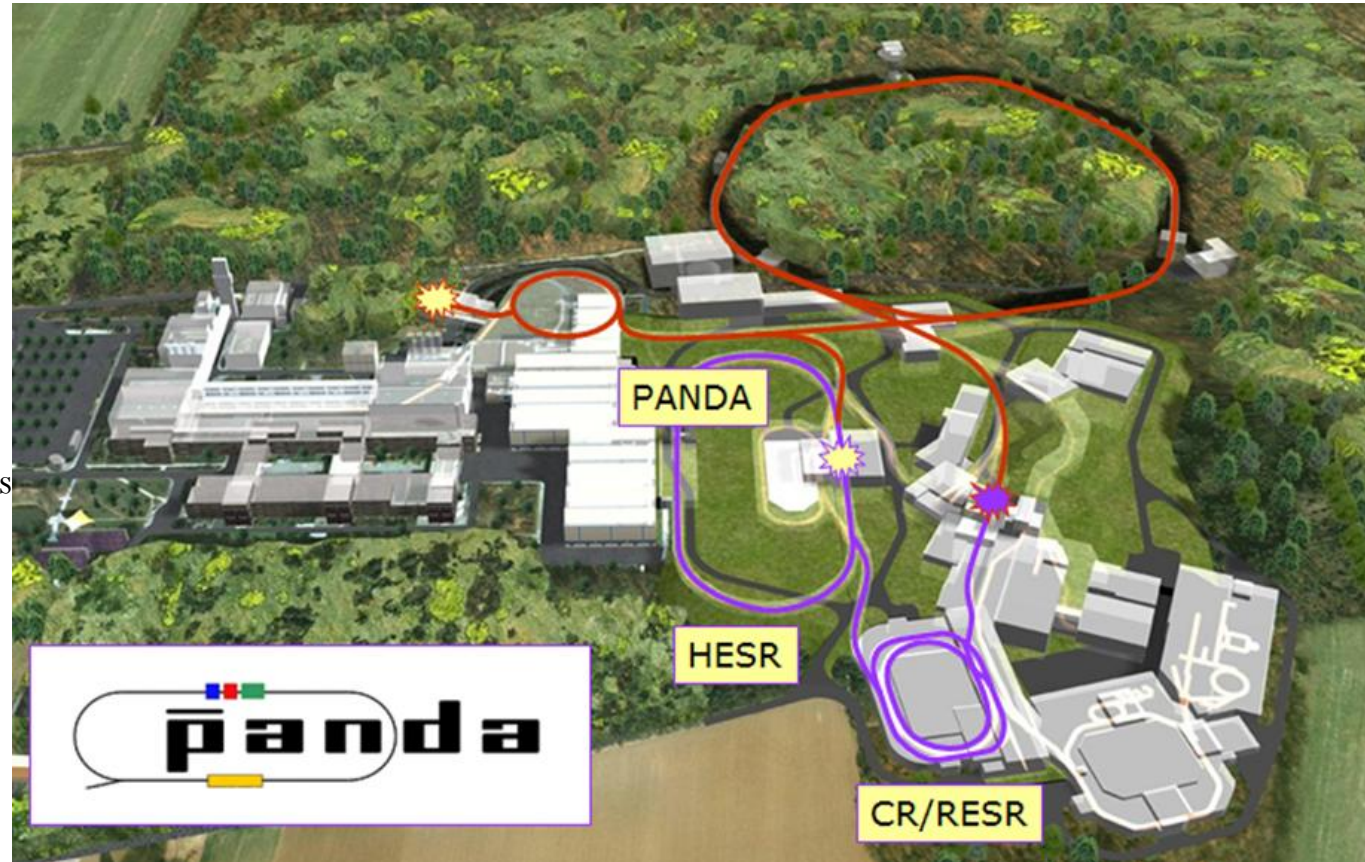
FAIR: New facility

Rare Isotope Beams

Heavy ions

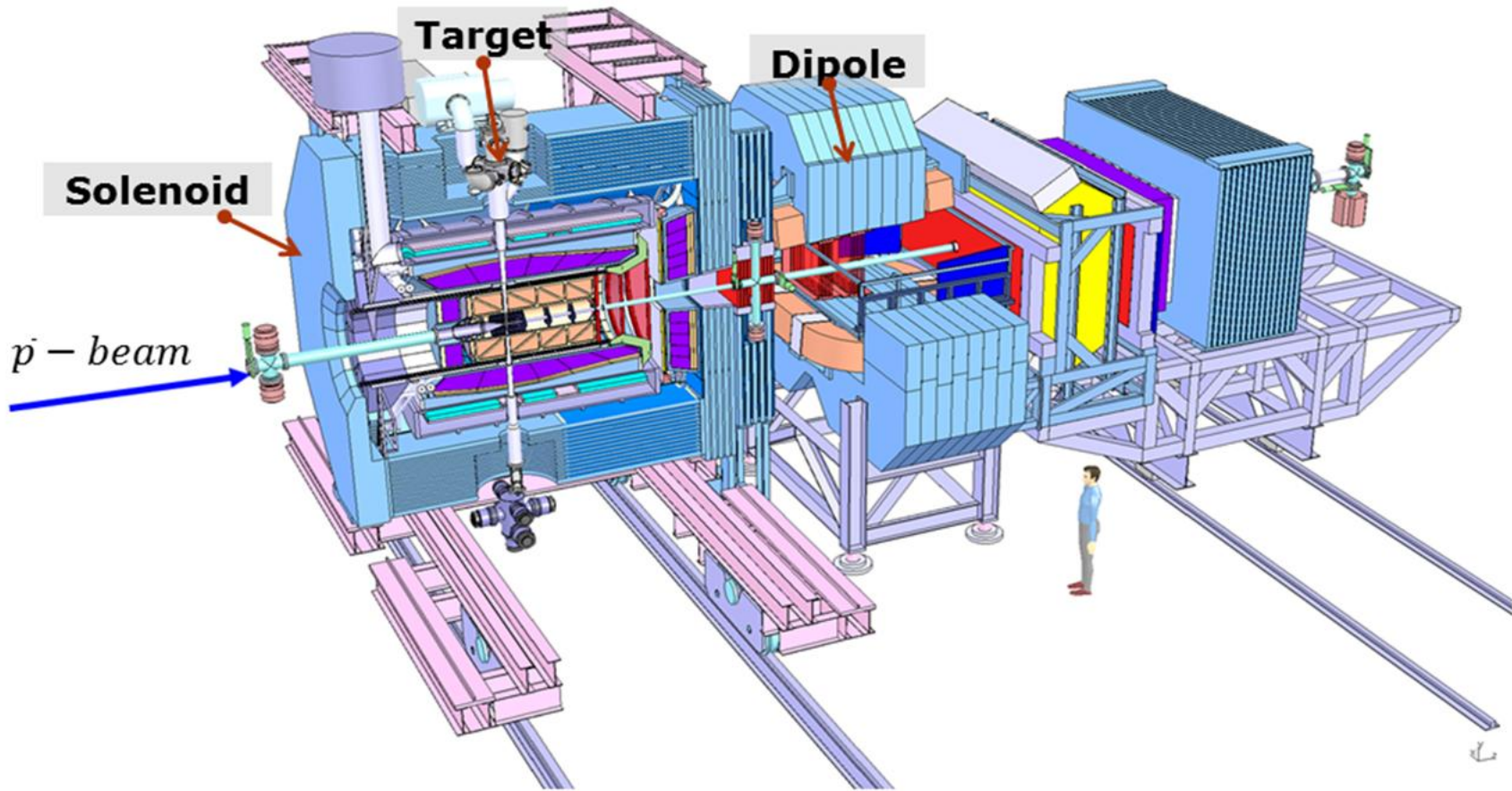
- higher intensities
& energies

Antiprotons





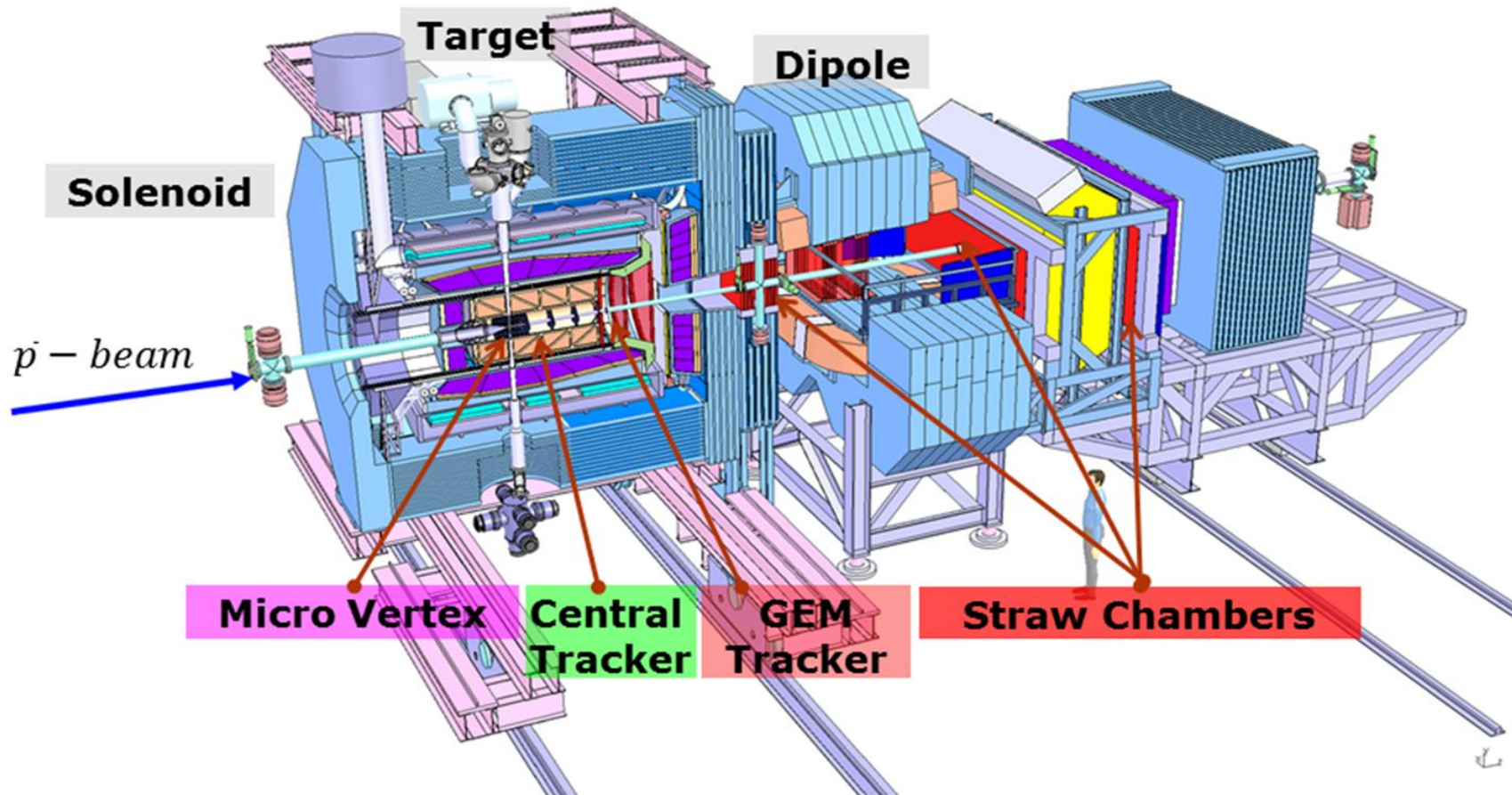
PANDA Detector





TARGET SPECTROMETER

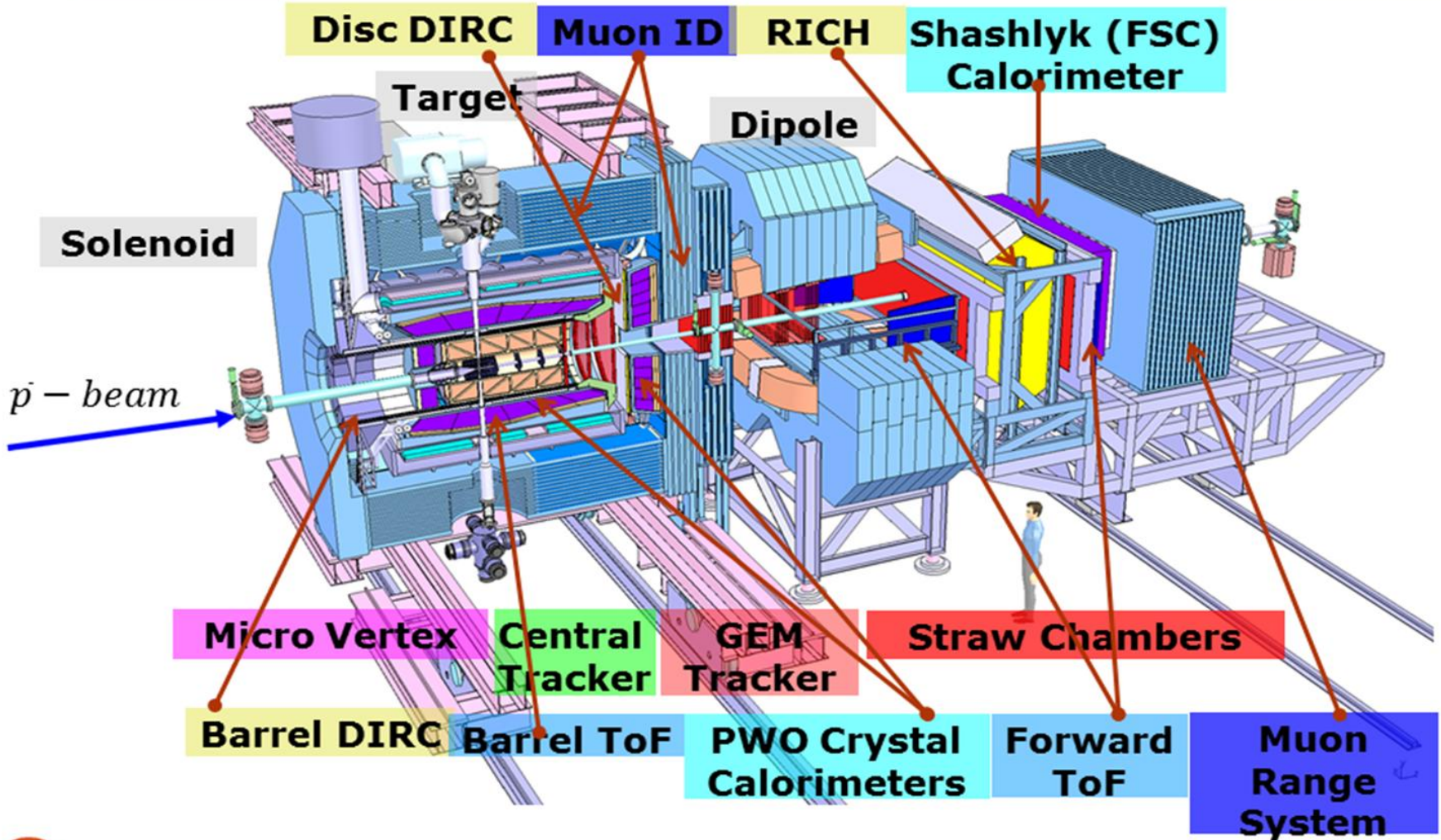
FORWARD SPECTROMETER





TARGET SPECTROMETER

FORWARD SPECTROMETER





Target Spectrometer EMC

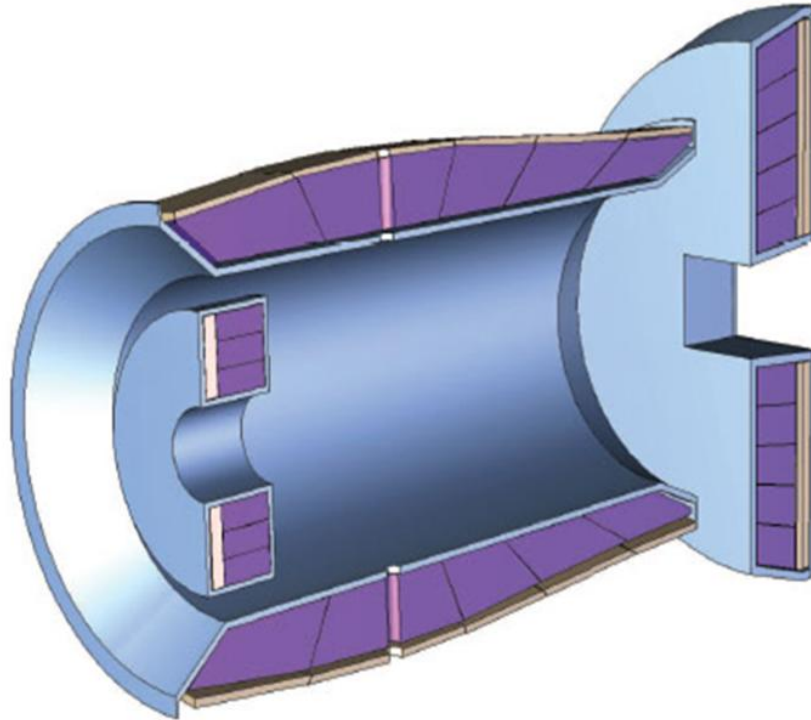
Barrel Calorimeter

- 11360 PWO Crystals
- LAAPD readout, $2 \times 1 \text{ cm}^2$

Forward EndCap

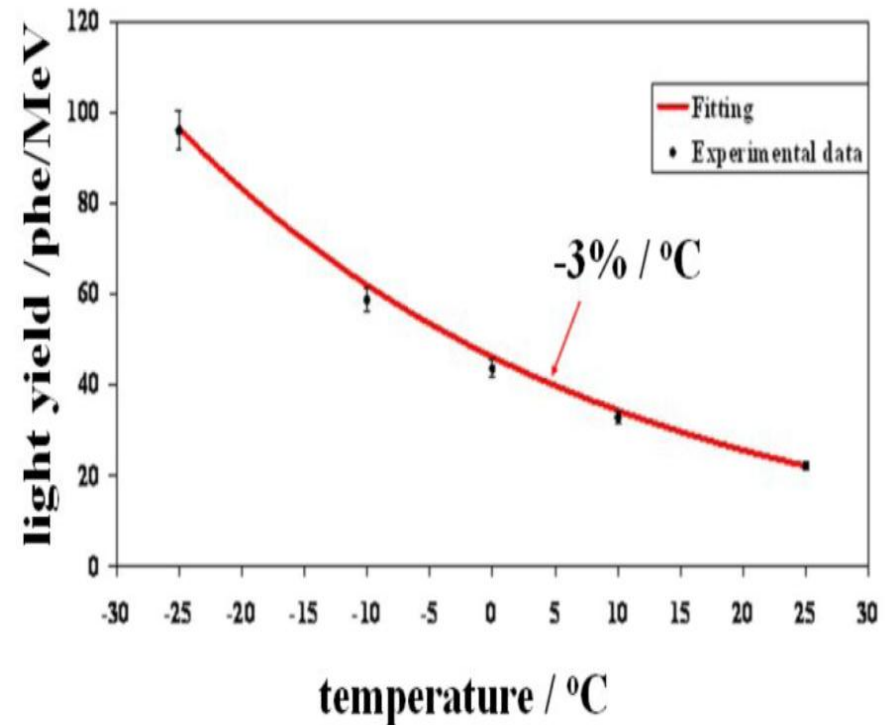
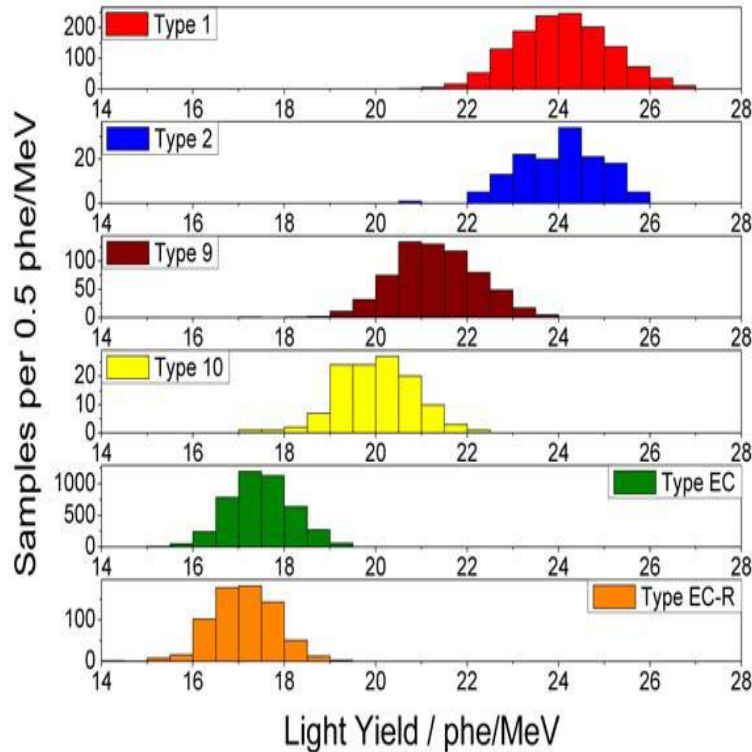
- 4000 PWO crystals
- High occupancy in center
- LAAPD or VPT

Backward EndCap
for hermeticity, 560 PWO crystals





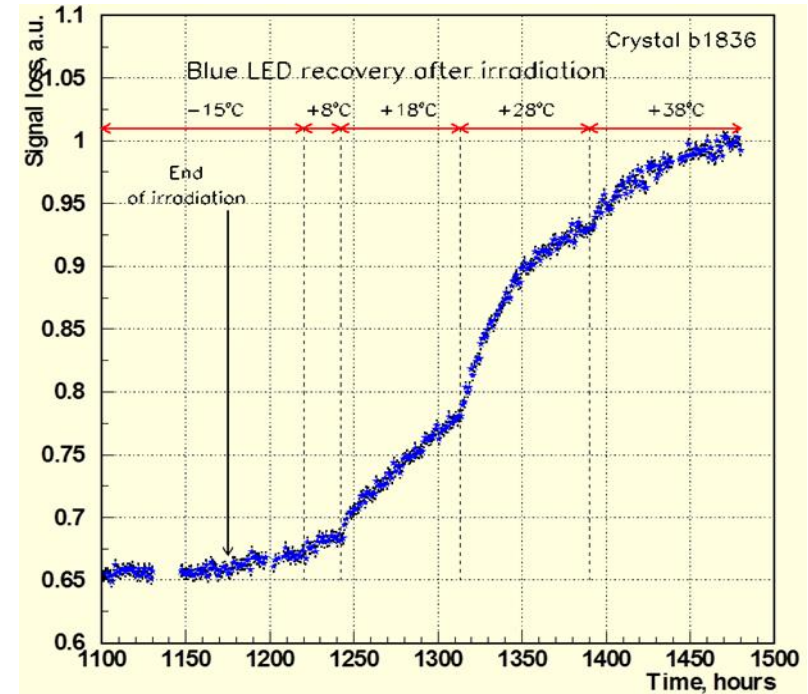
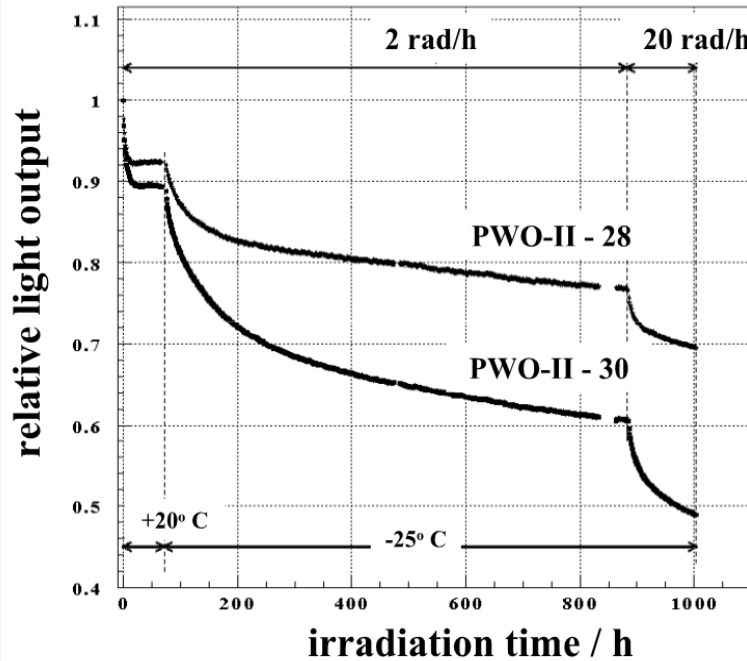
PWO-II light yield



PWO-II has two times more light yield than CERN (CMS type) crystals
 Temperature gives additional factor of 4 in light yield (total factor 8).



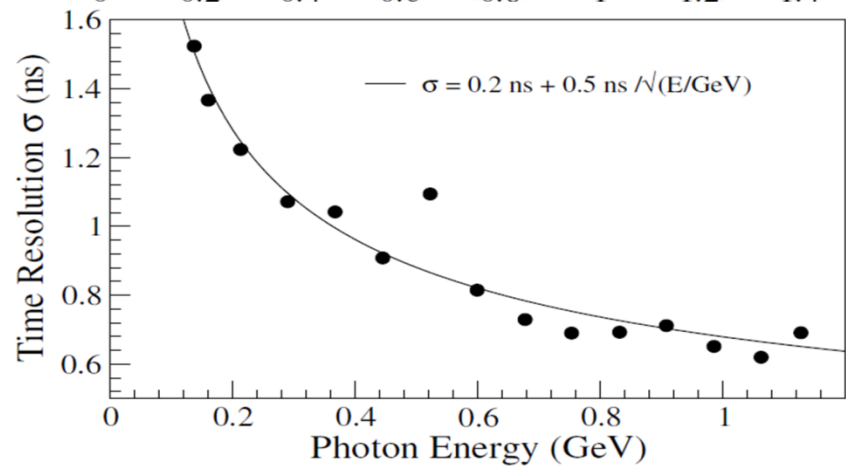
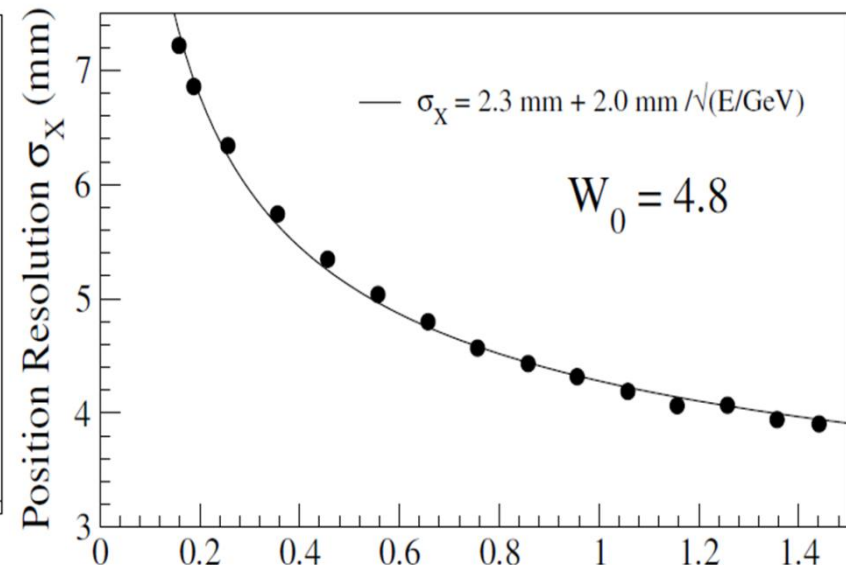
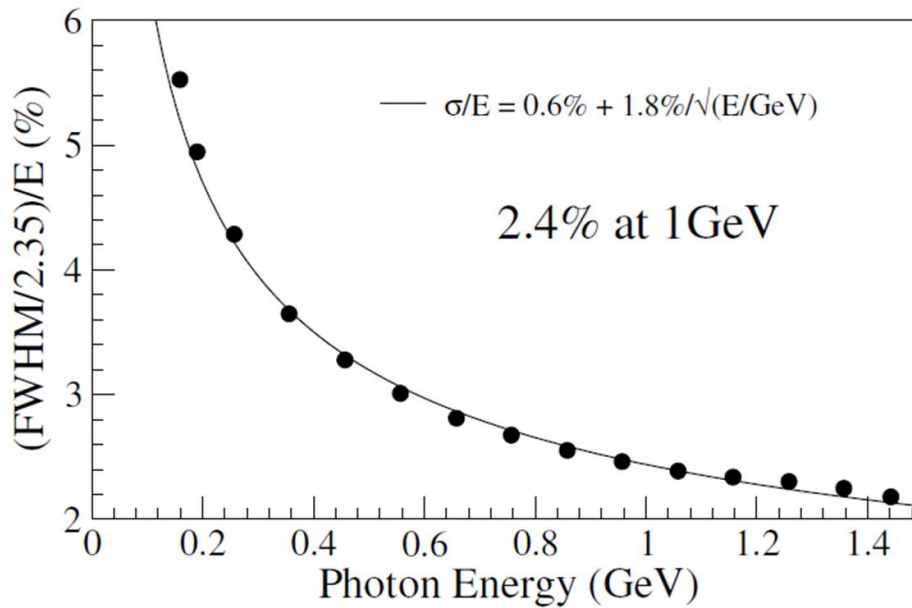
Signal loss after irradiation



- PWO crystals lose the transparency under irradiation
 - Good monitoring and calibration is required
- BUT – temperature recovery works,
 - Recovery by stimulation with infrared light is under study



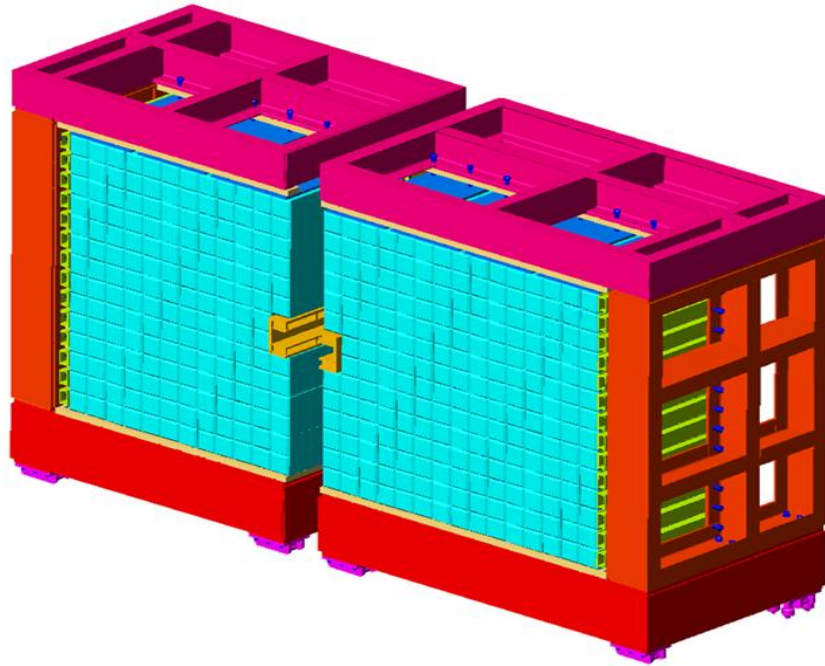
Target Spectrometer EMC performance



Module threshold is 0.75 MeV.



FSC construction



Detector size: ~3,6m x 2,2 m
(54x28 cells)

- 380 layers of 0.3-mm lead and 1.5-mm scintillator, total length 680 mm
- Transverse size 55x55 mm²
- Light collection: 36 fibers BCF-91A (Ø1.0 mm)
- PMT as a photodetector
- LED for each module as a light monitoring system
- Optical fiber for each cell for a precise PMT gain monitoring



FSC performance

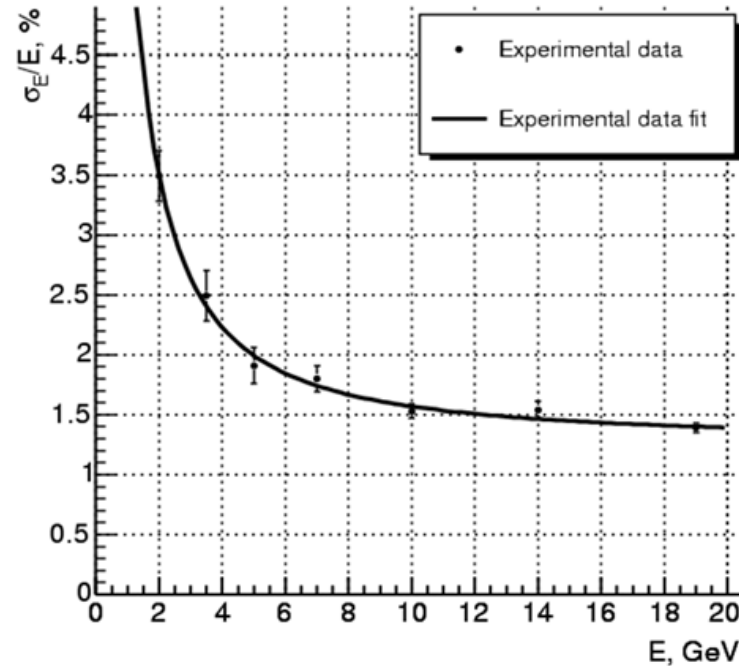
Energy resolution

- stochastic term 2.4%
- constant term 1.3 %

Position resolution at 19 GeV (measured with e- beam)

- 3 mm at cell center
- 1.5 mm at cell edge

Detection energy threshold and performance at low energies to be measured at Mainz this Fall





FSC performance

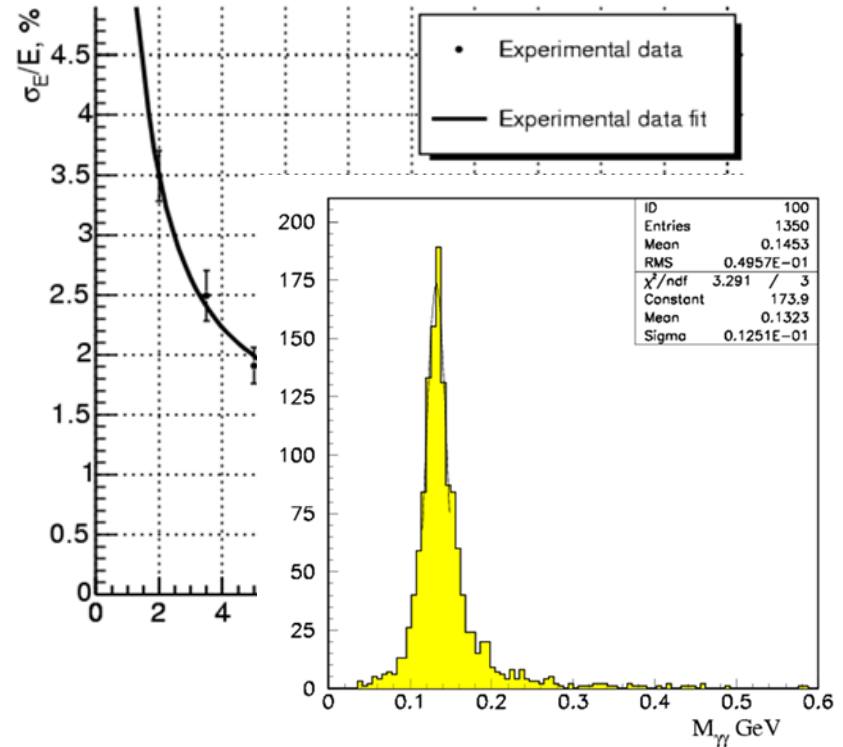
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Position resolution at 19 GeV (measured with e- beam)

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Detection energy threshold and performance at low energies to be measured at Mainz this Fall



π^0 1-2 GeV, σ_m 12.5 MeV



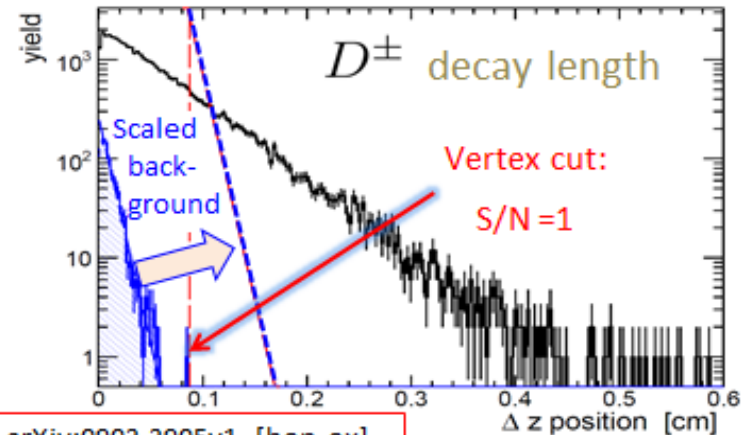
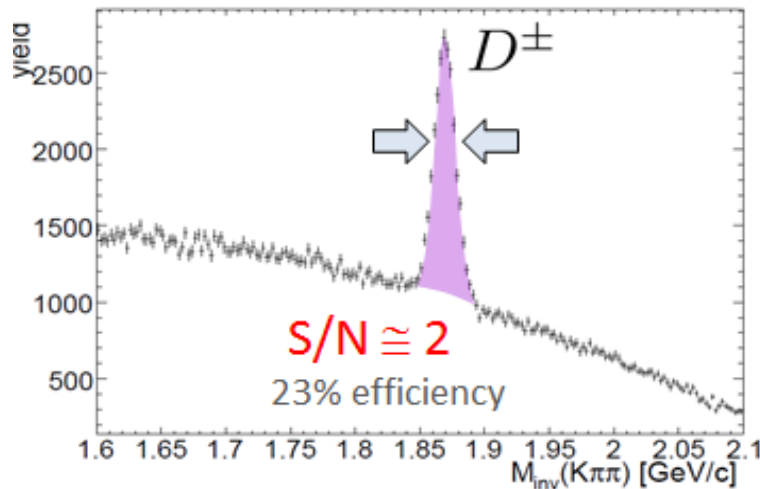
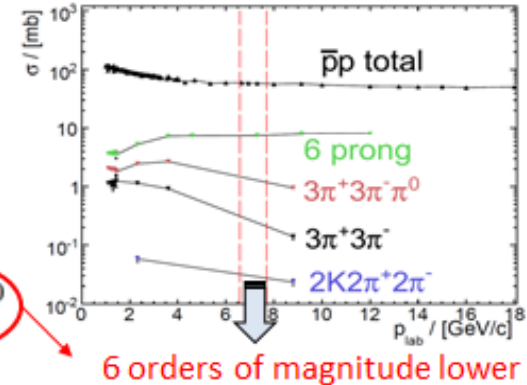
MVD physics – open charm

- Physics analysis $\bar{p}p \rightarrow D^+ D^-$

➤ Reconstruction: $D^\pm \rightarrow K^\mp \pi^\pm \pi^\pm$

$$R = \frac{\sigma(\bar{p}p \rightarrow D^+ D^-)}{\sigma(\bar{p}p \rightarrow X)} = \frac{2.83 \text{ nb} \cdot (0.092)^2}{60 \text{ mb}} = 4.0 \cdot 10^{-10}$$

Conservative estimate



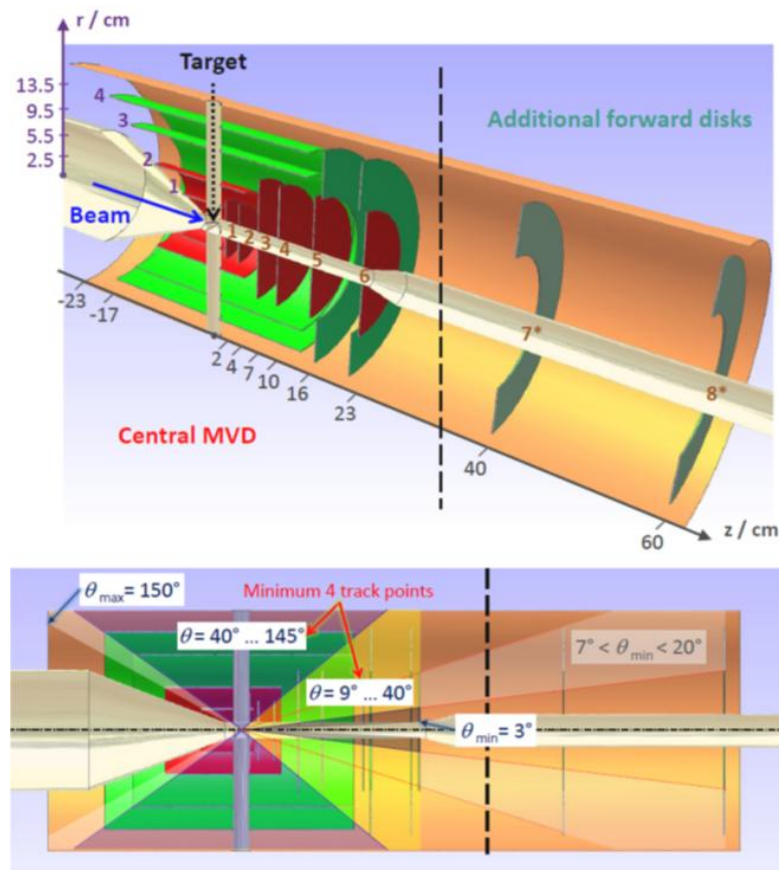
arXiv:0903.3905v1 [hep-ex]

- Background suppression for open charm channels impossible without MVD



MVD

- Basic layout of the MVD and the two additional disks in forward direction (top).
 - The **red** (inner parts) are equipped with silicon hybrid pixel sensors.
 - Double-sided silicon micro-strip detectors in the outer layers are **in green**.
 - The additional forward disks (7 and 8) are based on the design of the outer strip disks.
- Bottom: Illustration of the solid angle coverage.
 - The MVD covers polar angles, θ , from 3° up to 150° .
A minimum of four detector layers contribute in a range of $9^\circ < \theta < 145^\circ$



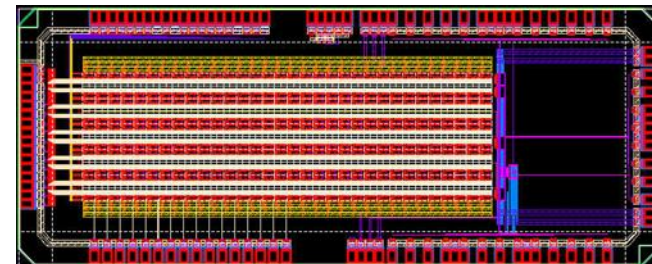
Pixel detector development: Front-end electronics



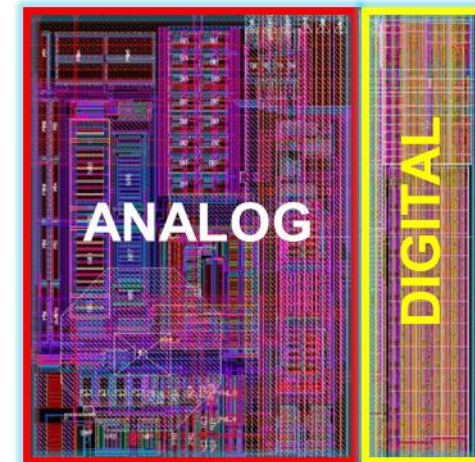
ToPix specifications:

Custom made pixel readout chip developed using 130 nm CMOS technology

Pixel readout size	100 μ m x 100 μ m
Chip active area	11.4 mm x 11.6 mm
dE/dx measurement	ToT, 12 bits dynamic range
Noise	<0.032 fC (200 e ⁻)
Clock frequency	155.52 MHz
Time resolution	6.4 ns (1.85 ns rms)
Power consumption	<<500 mW/cm ²
Max. event rate @2·10 ⁷ pbar-p ann/s:	~ 12·10 ⁶ hits/(cm ² ·s)



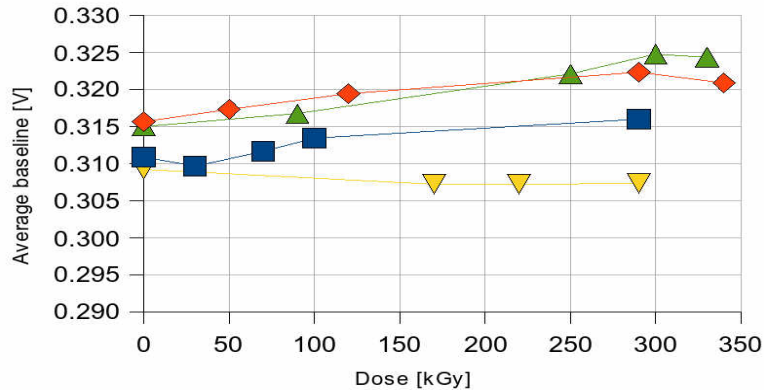
Prototype with 320 readout cells



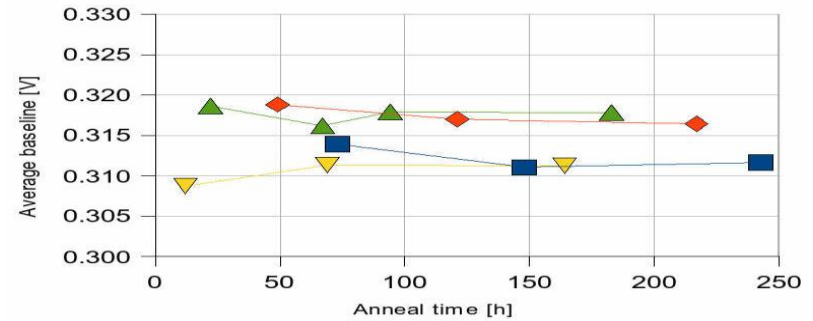
Pixel readout cell,
100 μ m x 100 μ m size



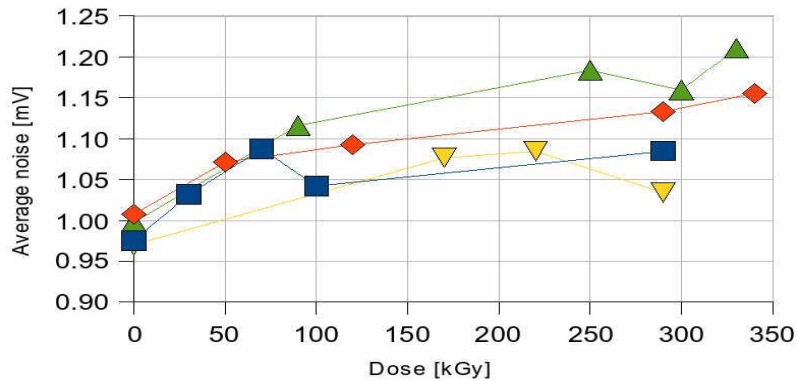
Irradiation test ToPix2



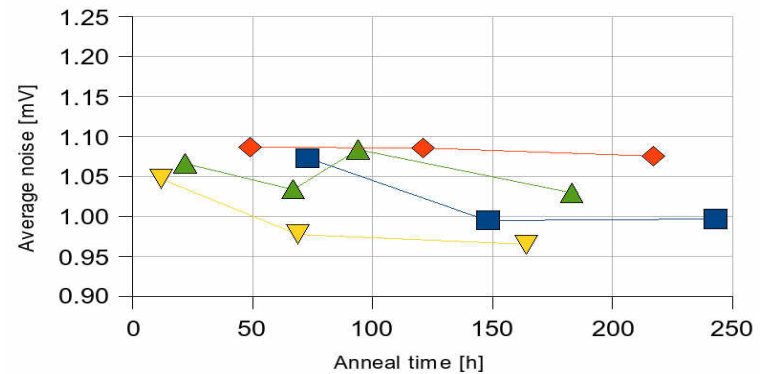
Average baseline during irradiation



Average baseline during annealing



Average noise during irradiation



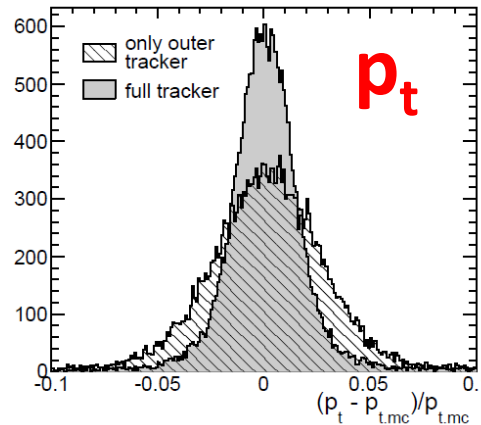
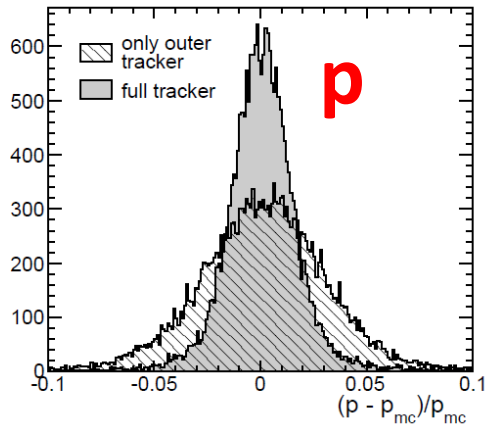
Average noise during annealing



Momentum resolution (simulation)

Momentum resolution

1 GeV/c pions (0;0;0)

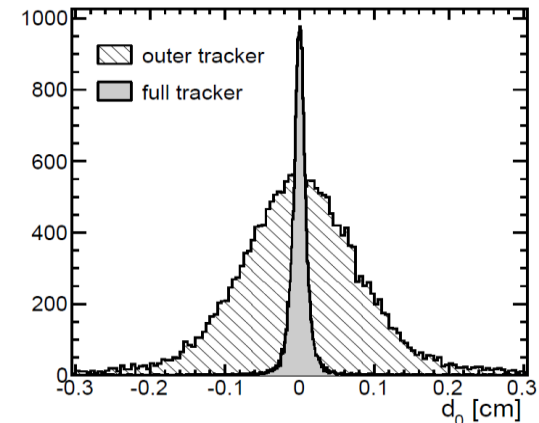
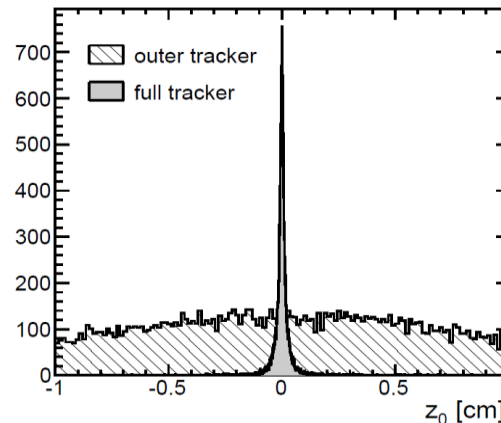


$\sigma(p)$ without MVD = 2.6 %
 $\sigma(p)$ with MVD = 1.4 %
 $\sigma(p_t)$ without MVD = 2.9 %
 $\sigma(p_t)$ with MVD = 1.4 %

→ Improvement by 50%

Single track resolution

→ No resolution along z without MVD





PANDA R&D and construction strategy



- 2011 and 2012 – tests at CERN (RE22)
- End 2011 to have TDR for each sub-detector
 - 2 TDR's are approved
 - 3 TDR are submitted
- 2012 start detector construction
- 2015 - assembling and tests at Juelich parts of detectors
- 2017 - PANDA Detector assembly at Darmstadt
- Total Price 66.3 M Euro (in January 2005 costs)



Backup slides



High Energy Storage Ring



Parameter

- Injection of \bar{p} at 3.7 GeV
- Slow synchrotron (1.5-15.0 GeV/c)
- Luminosity up to $L \sim 2 \times 10^{32} \text{ cm}^{-2} \text{ s}^{-1}$
- Beam cooling (stochastic & electron) $\Rightarrow \Delta p/p \leq 4 \cdot 10^{-5}$
- **Resonance scan:**
 - Energy resolution down to $\sim 50 \text{ keV}$
 - Tune E_{CM} to probe resonance
 - Get precise mass and width

Mode	High Resolution	High Luminosity
Momentum range	1.5 - 8.9 GeV/c	1.5 - 15 GeV/c
Stored antiprotons	10^{10}	10^{11}
Luminosity	$2 \cdot 10^{31} \text{ cm}^{-2} \text{ s}^{-1}$	$2 \cdot 10^{32} \text{ cm}^{-2} \text{ s}^{-1}$
Mom. Resol. (rms)	$\Delta p/p \leq 4 \cdot 10^{-5}$	$\Delta p/p = 1 \cdot 10^{-4}$
Beam cooling	Electron ($\leq 8.9 \text{ GeV/c}$)	Stochastic ($\geq 3.8 \text{ GeV/c}$)



PANDA Detector requirements

- Nearly 4π solid angle for PWA
- High rate capability: $2 \cdot 10^7 \text{ s}^{-1}$ interactions
- Momentum resolution better 1%
- Vertex info for D, K_0 , Σ , Λ ($c\tau = 317 \text{ }\mu\text{m}$ for D^\pm)
- Good PID (γ , e, μ , π , K, p)
- Photon detection 1 MeV – 15 GeV



Other sub-detectors

- **Target** – cluster or pellet
- **Central tracker** (Resolution: $\sigma_{r\phi} \sim 150\mu\text{m}$, $\sigma_z \sim 1\text{mm}$, $\delta p/p \sim 1\%$ Material budget $\sim 1\% X_0$)
 - **Straw Tube Tracker** (27 μm thin mylar tubes, 1 cm \O , 8 skewed layers, 27 total, or 4500 channels)
 - **Or GEM Time Projection Chamber** (Approx. 100k channels, TPC gas NeCO_2)
- **Muon system layout:** (Drift tubes with wire and cathode strip readout, Iron absorbers)
 - *Barrel:* 12+2 layers in yoke
 - *Endcap:* 5+2 layers
 - *Muon Filter:* 4 layers
 - *Forward Range System:* 16+2 layers

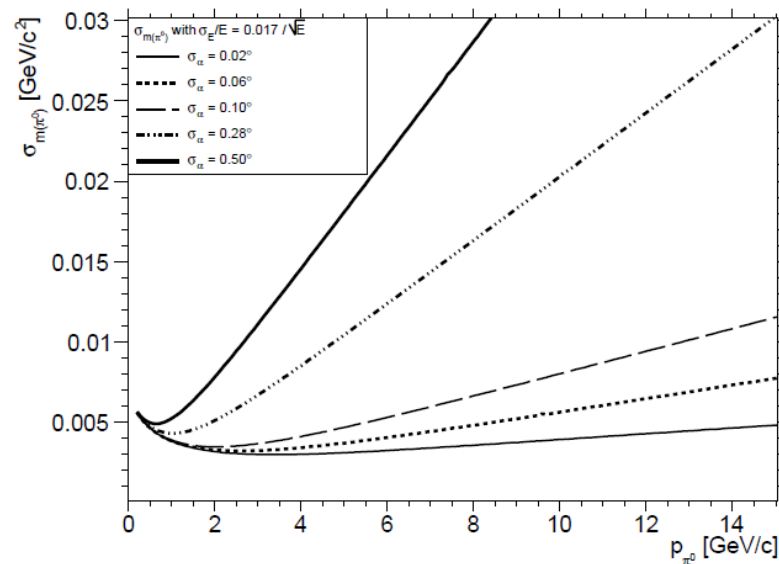
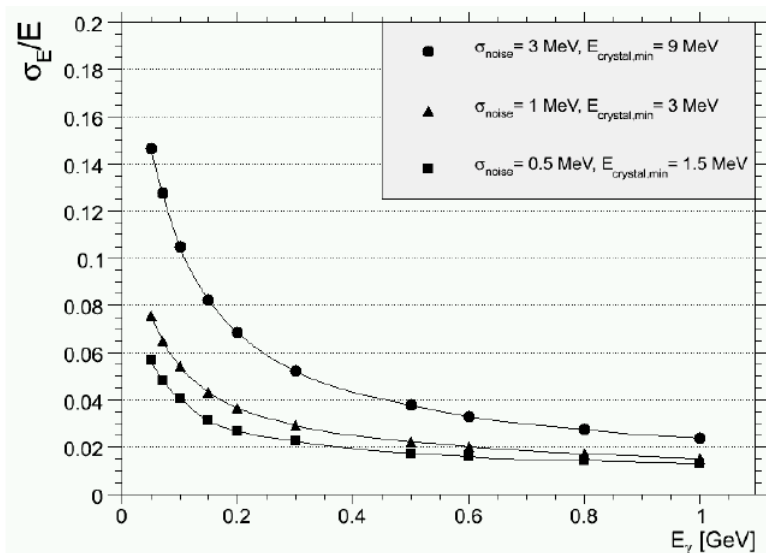


PANDA EMC requirements

	Required performance value		
Common properties			
energy resolution σ_E/E	$\leq 1\% \oplus \frac{\leq 2\%}{\sqrt{E/\text{GeV}}}$		
energy threshold (photons) E_{thres}	10 MeV (20 MeV tolerable)		
energy threshold (single crystal) E_{xtl}	3 MeV		
rms noise (energy equiv.) $\sigma_{E,noise}$	1 MeV		
angular coverage $\% 4\pi$	99 %		
mean-time-between-failures t_{mtbf} (for individual channel)	2000 y		
Subdetector specific properties			
	backward ($\geq 140^\circ$)	barrel ($\geq 22^\circ$)	forward ($\geq 5^\circ$)
energy range from E_{thres} to	0.7 GeV	7.3 GeV	14.6 GeV
angular equivalent of crystal size θ	4°		1°
spatial resolution σ_θ	0.5°	0.3°	0.1°
maximum signal load f_γ ($E_\gamma > E_{xtl}$)	60 kHz		500 kHz
(p \bar{p} -events) maximum signal load f_γ ($E_\gamma > E_{xtl}$)	100 kHz		500 kHz
(all events) shaping time t_s	400 ns		100 ns
radiation hardness	0.15 Gy	7 Gy	125 Gy
(maximum annual dose p \bar{p} -events)			
radiation hardness	10 Gy		125 Gy
(maximum annual dose from all events)			



EMC required resolutions



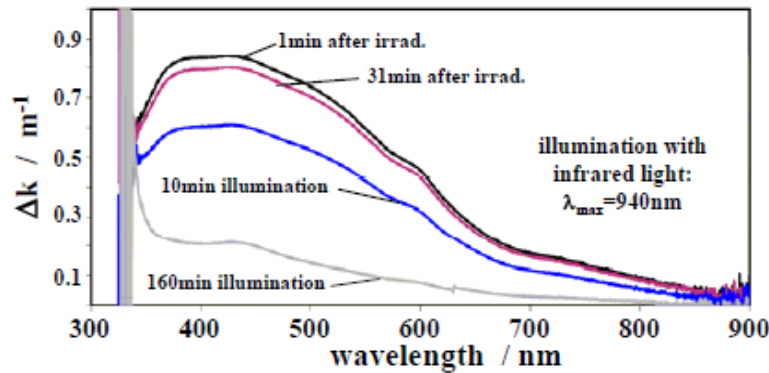
Comparison of the energy resolutions for three different single crystal reconstruction thresholds.

- noise 0.5 MeV, $E(\text{single}) = 1.5 \text{ MeV}$
- noise 1 MeV, $E(\text{single}) = 3 \text{ MeV}$
- noise 3 MeV, $E(\text{single}) = 9 \text{ MeV}$

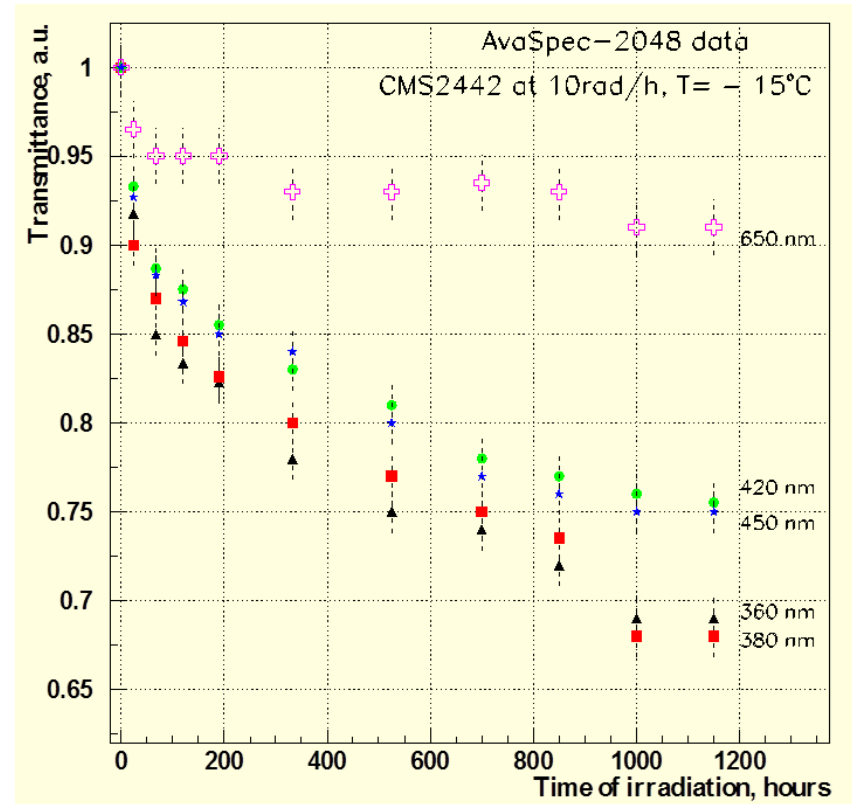
π^0 mass resolution for various spatial resolution values vs. beam momentum.

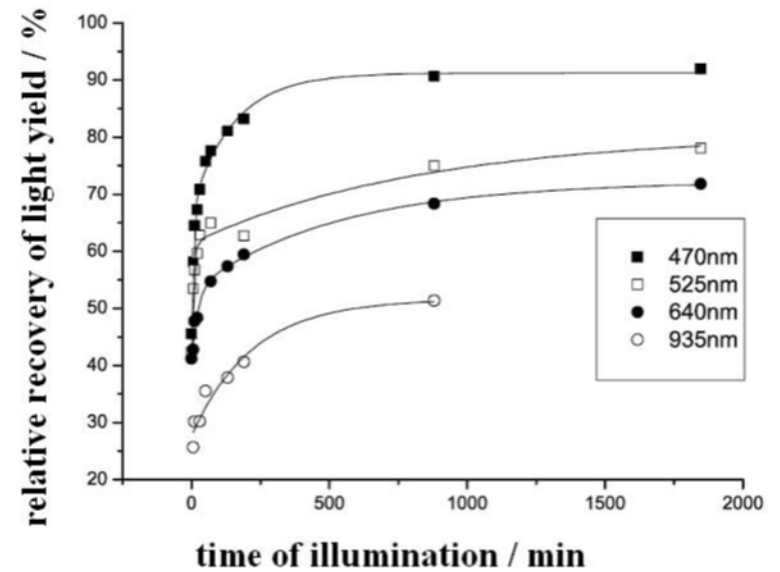
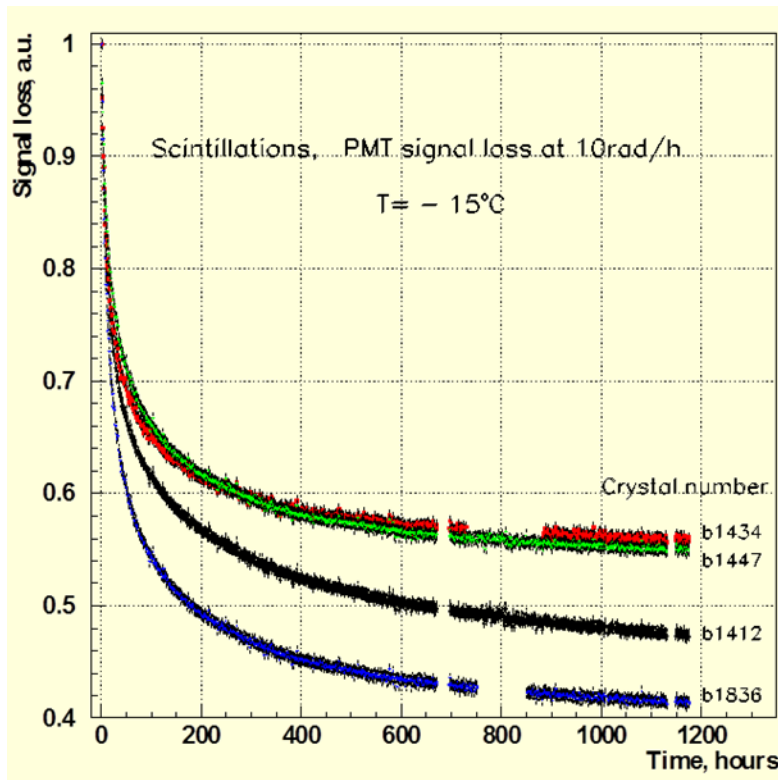


Transparency loss under irradiation



Change of the full spectral distribution of the induced absorption coefficient of a PWO-II crystal after irradiation with an integral dose of 30Gy measured at room temperature. The spectra are measured 1 and 31 minutes after irradiation as well as after additional illumination for 10 and 160 minutes, respectively, with infrared light at 940nm.





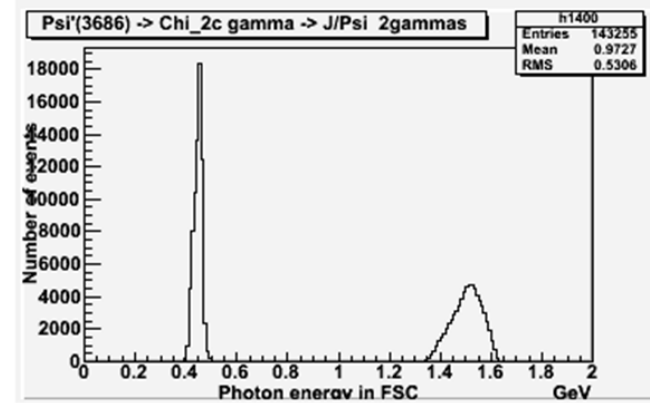
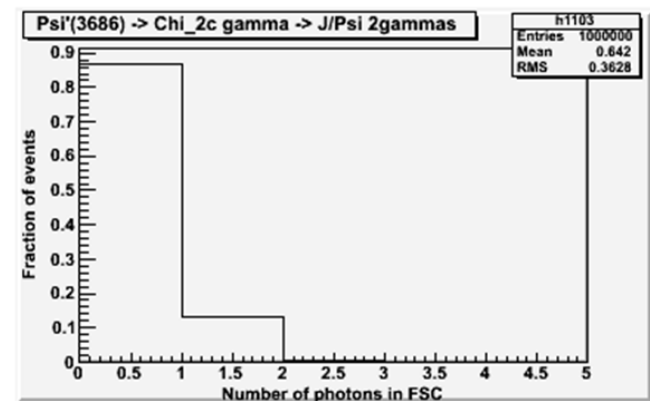
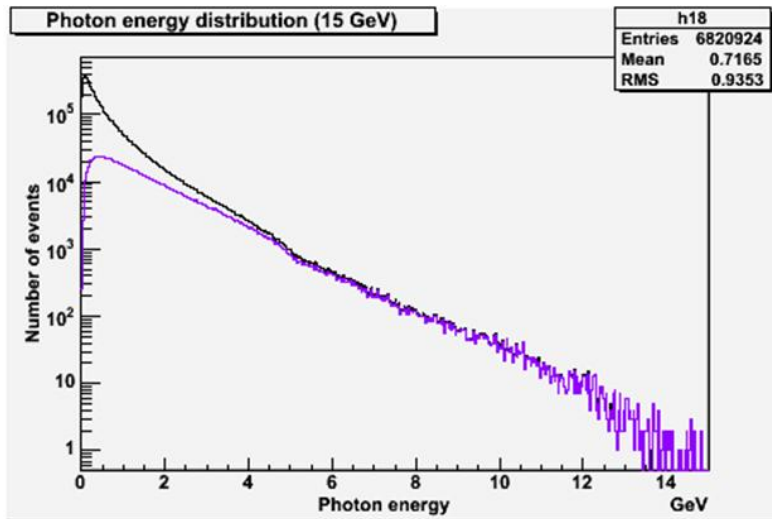
Forward spectrometer calorimeter (FSC) requirements



Important to have closed geometry for PWA.

Photons energy from 0 to 15 GeV

**Charmonium study,
6.27 GeV/c beam**



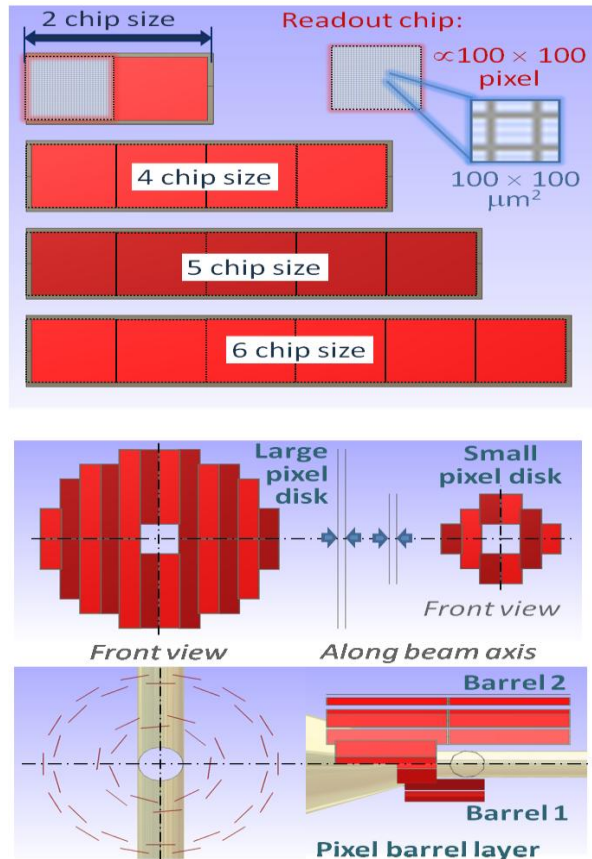
EMC electronics

- Barrel EMC: First realistic mechanical design for the SADC s is ready
- Commercial SADC (Struck SIS3302): (8 channels, 16 bit (input range – 5V single-ended or 1V differential), up to 100 Msp/s, Customized firmware with PANDA feature-extraction algorithm
- OR 14 bit $\pm 1V$ differential or $\pm 2V$ differential), 125 Msp/s, Virtex-5 FPGA (XC5FX70T)
- The EMC SADC is expected to be available by the end of this year (hardware)



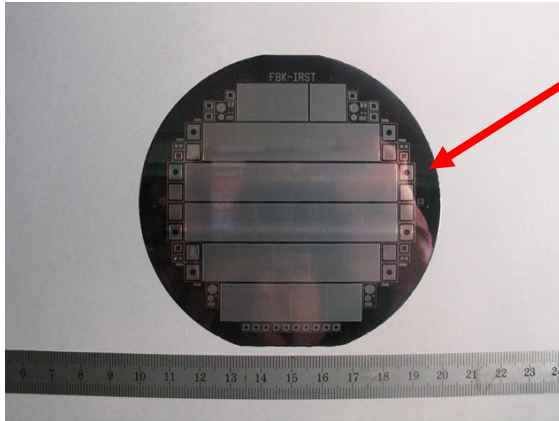


PANDA MVD pixel sensor

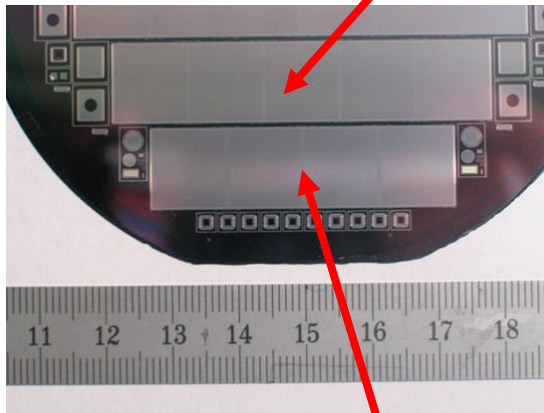


- Schematics of the basic pixel sensor geometry.
- Top: Main pixel sensor types. The design is based on a quadratic pixel cell size of $100 \times 100 \mu\text{m}$ and an effective readout area of approximately 1 cm per individual readout chip.
- Bottom: Pixel sensor arrangement in different detector layers.

Pixel detector development: sensor

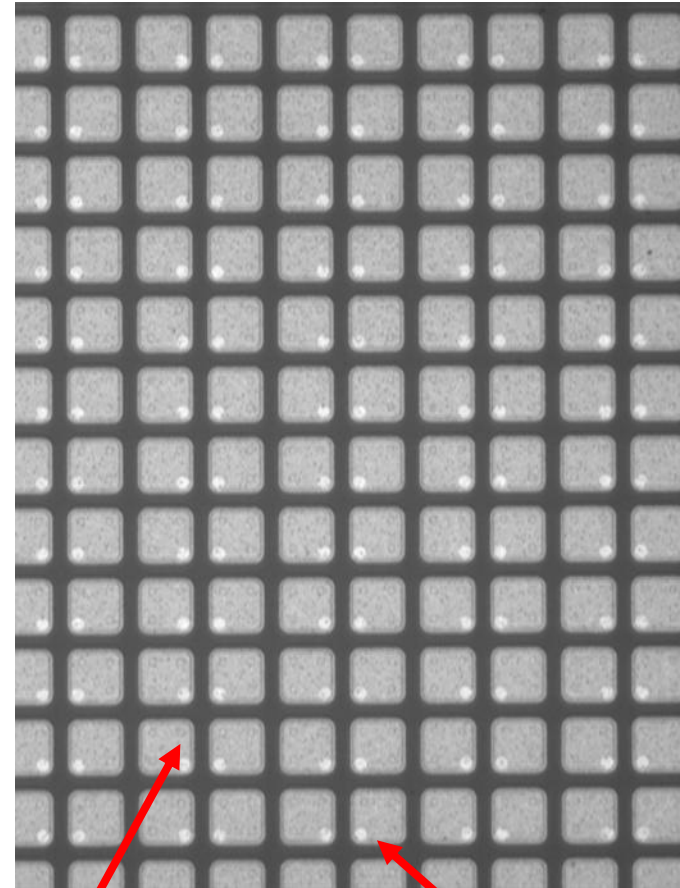


Epitaxial wafer with sensor: first design



5 readout chip sensor

4 readout chip sensor



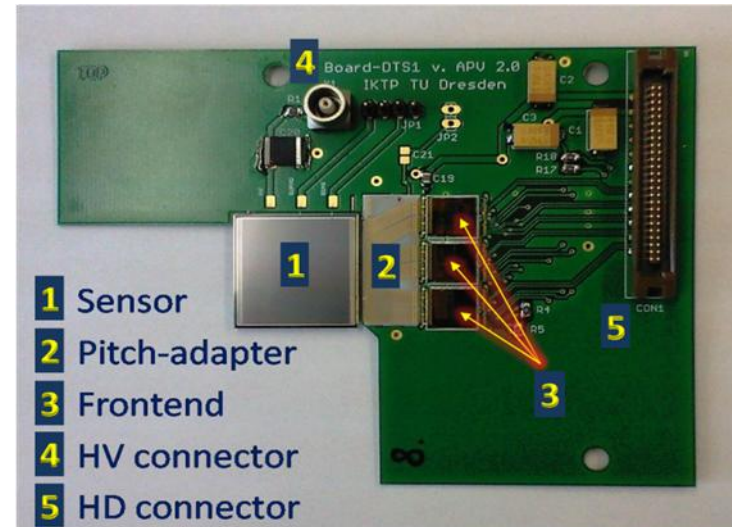
pixel

Pad for bump bonding



Strip detector development

- Different sensor types are used:
- rectangular shape with a stereo angle of 90° and readout pitch of $130 \mu\text{m}$ (barrel part)
- trapezoidal shape with a stereo angle of 15° and readout pitch of $70 \mu\text{m}$ (disk part) $200 \mu\text{m}$ thickness

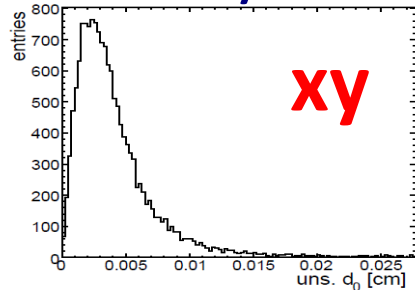


Sensor:
 2 cm side length
 $300 \mu\text{m}$ thickness
 90° stereo angle
 $50 \mu\text{m}$ pitch
 Readout: APV25 – S1

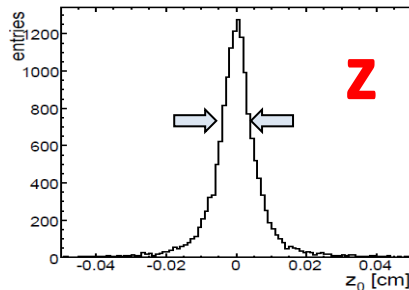


MVD resolution (simulation)

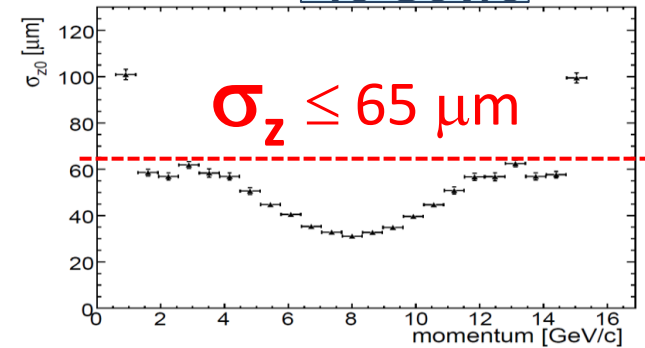
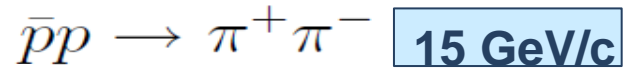
- Primary vertex resolution



xy



z



$\sigma_z \leq 65 \mu\text{m}$

- Vertex resolution $\bar{p}p \rightarrow D^+ D^-$ (6.57 / 7.50 / 8.50) GeV/c

momentum GeV/c	primary			secondary		
	$\sigma_{prim,x}$	$\sigma_{prim,y}$	$\sigma_{prim,z}$	$\sigma_{sec,x}$	$\sigma_{sec,y}$	$\sigma_{sec,z}$
6.57	30.7	30.7	493.6	35.4	35.2	77.1
7.50	30.4	30.3	208.5	37.1	36.4	84.0
8.50	30.0	29.0	157.4	36.7	36.2	92.4

→ Primary and secondary vertex resolution:

$\sigma_{x,y} \leq 35 \mu\text{m}$

$\sigma_z \leq 100 \mu\text{m}$